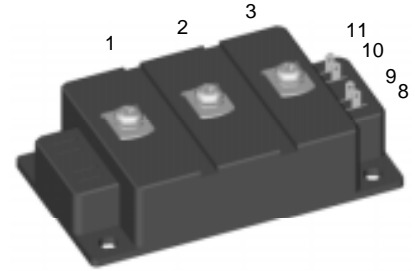
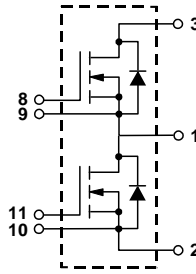


MOSFET Module with ultrafast Schottky Diode

VMM 600-0075 S
 $V_{DSS} = 75\text{ V}$
 $I_{D25} = 590\text{ A}$
 $R_{DS(on)} = 1.1\text{ m}\Omega$

N-Channel Enhancement Mode


 1 = Drain 1, Source 2 2 = Source 1
 3 = Drain 2 8 = Gate 2
 9 = Kelvin Source 2 10 = Kelvin Source 1
 11 = Gate 1

Symbol	Test Conditions	Maximum Ratings	
V_{DSS}	$T_J = 25^\circ\text{C to } 150^\circ\text{C}$	75	V
V_{DGR}	$T_J = 25^\circ\text{C to } 150^\circ\text{C}; R_{GS} = 10\text{ k}\Omega$	75	V
V_{GS}	Continuous	± 20	V
V_{GSM}	Transient	± 30	V
I_{D25}	$T_S = 25^\circ\text{C}$	590	A
I_{D80}	$T_S = 80^\circ\text{C}$	440	A
I_{DM}	$T_S = 25^\circ\text{C}$ pulse width limited by T_{JM}	2360	A
P_D	$T_C = 25^\circ\text{C}$	1040	W
	$T_S = 25^\circ\text{C}$	690	W
T_J		-40 ... +150	$^\circ\text{C}$
T_{JM}		150	$^\circ\text{C}$
T_{sig}		-40 ... +125	$^\circ\text{C}$
V_{ISOL}	50/60 Hz $t = 1\text{ min}$	3000	V~
	$I_{ISOL} \leq 1\text{ mA}$ $t = 1\text{ s}$	3600	
M_d	Mounting torque (M6)	2.25-2.75/20-25	Nm/lb.in.
	Terminal connection torque (M5)	2.5-3.7/22-33	Nm/lb.in.
Weight	typical including screws	250	g

Features

- International standard package
- Direct Copper Bonded Al_2O_3 ceramic base plate
- Isolation voltage 3600 V~
- Low $R_{DS(on)}$ HDMOS™ process
- Low package inductance for high speed switching
- Ultrafast Schottky Diode for less switching losses and less RFI

Symbol	Test Conditions	Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified)		
		min.	typ.	max.
V_{DSS}	$V_{GS} = 0\text{ V}, I_D = 5\text{ mA}$	75		V
$V_{GS(th)}$	$V_{DS} = 20\text{ V}, I_D = 2.5\text{ mA}$	2		5 V
I_{GSS}	$V_{GS} = \pm 20\text{ V DC}, V_{DS} = 0$			$\pm 1\text{ }\mu\text{A}$
I_{DSS}	$V_{DS} = 0.8 \cdot V_{DSS}$ $V_{GS} = 0\text{ V}$	$T_J = 25^\circ\text{C}$		TBD mA
		$T_J = 125^\circ\text{C}$		TBD mA
$R_{DS(on)}$	$V_{GS} = 10\text{ V}, I_D = 0.5 \cdot I_{D25}$ Pulse test, $t \leq 300\text{ }\mu\text{s}$, duty cycle $d \leq 2\%$			1.1 m Ω

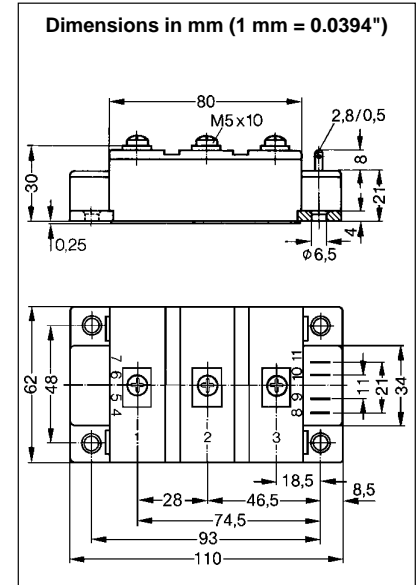
Applications

- AC motor speed control for electric vehicles
- DC servo and robot drives
- DC choppers

Advantages

- Easy to mount
- Space and weight savings
- High power density
- Low losses

Symbol	Test Conditions	Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified)		
		min.	typ.	max.
g_{fs}	$V_{DS} = 10\text{ V}; I_D = 0.5 \cdot I_{D25}$ pulsed		270	S
C_{iss}	$V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$		45	nF
C_{oss}			8	nF
C_{rss}			2	nF
$t_{d(on)}$	$V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$		70	ns
t_f			100	ns
$t_{d(off)}$			70	ns
t_r			30	ns
Q_g	$V_{GS} = 30\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 600\text{ A}$		770	nC
Q_{gs}			280	nC
Q_{gd}			220	nC
R_{thJC}				0.12 K/W
R_{thJS}	with 30 μm heat transfer paste		0.18	K/W



Symbol	Test Conditions	Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified)		
		min.	typ.	max.
I_F	$V_{GS} = 0\text{ V}$			510 A
I_{FSM}	Repetitive; pulse width limited by T_{JM}			TBD A
V_F	$I_F = 600\text{ A}; V_{GS} = 0\text{ V},$ Pulse test, $t \leq 300\ \mu\text{s}$, duty cycle $d \leq 2\%$		1.05	V
I_{RM}	$I_F = I_S, -di/dt = 1000\text{ A}/\mu\text{s}, V_{DS} = 0.5 \cdot V_{DSS}$		TBD	A
t_{rr}			TBD	ns
R_{thJC}	Diode			0.19 K/W
R_{thJK}	package with 30 mm heat transfer paste		0.28	K/W